

**Claim Amendments:**

This listing of claims will replace all prior versions, and listings of claims in the application:

1. (Currently Amended) An adaptive resonant power converter comprising:  
a gate drive transformer comprising a first sensing primary winding, a first secondary winding, and a second secondary winding;[[;]]  
a first MOSFET having a gate connected to said first secondary winding;  
a second MOSFET having a gate connected to said second secondary winding;  
said first and second MOSFETS connected to each other in series across a direct current input source and forming a common MOSFET node therebetween at said first MOSFET source and said second MOSFET drain;  
a main transformer comprising a primary winding and a first resonant output winding;  
an input capacitor having a first capacitor node connected to said first MOSFET drain and a second capacitor node connected to said main transformer primary winding;  
said main transformer primary winding connected between said common MOSFET node and said second capacitor node; and  
wherein a first tap of said first resonant output winding is connected to a first tap of said first sensing primary winding, a second tap of said first resonant output winding is connected to a first load terminal of a first load, and a second tap of said first sensing primary winding is connected to a second load terminal of said first load.

2. (Currently Amended) The converter according to claim 1 wherein said gate drive switching transformer further comprises a protection diode winding connected in parallel with a pair of parallel voltage limiting diodes, said voltage limiting diodes having opposite orientations.

3. (Original) The converter according to claim 1 further comprising:  
a first rectifier diode connected between said first resonant output winding and said first load terminal;  
a second output circuit having second resonant output winding on said main transformer with the same number of turns as said first resonant output winding;  
a second sensing primary winding on said gate drive transformer having the same number of turns as said first primary output winding;  
wherein a first tap of said second resonant output winding is connected to a first tap of said second sensing primary winding, a second tap of said second resonant output winding is connected through said second rectifier diode to a first load terminal, and a second tap of said second sensing primary winding is connected to said second load terminal;  
a second rectifier diode connected between said first load terminal and said second resonant output winding such that said first and second rectifier diodes are oriented in the same direction relative to said load; and  
a capacitor connected to the output of said first and second diodes.

4. (Original) The converter according to claim 1 further comprising one or more additional loads connected across corresponding additional resonant output windings on said main transformer wherein said first load is required to remain connected in a closed circuit with said first resonant output windings and said first sensing primary winding.

5. (Original) The converter according to claim 1 further comprising one or more additional loads connected across corresponding additional output windings on said main transformer; and a dedicated resonant output winding on said main transformer operatively connected to a corresponding dedicated primary sense winding on said gate drive transformer.

6. (Original) The converter according to claim 1 further comprising a compensation capacitor connected between the gate and source of each MOSFET to provide resonant oscillation with said first secondary winding and said second secondary winding.

7. (Original) The converter according to claim 1 further comprising a damping resistor connected in series between each of said MOSFET gates and its corresponding secondary winding on said gate drive transformer.

8. (Currently Amended) An adaptive resonant power converter comprising:

- a gate drive transformer comprising a first sensing primary winding, a first secondary winding, and a second secondary winding;[[;]]
- a first MOSFET having a gate connected to said first secondary winding;
- a second MOSFET having a gate connected to said second secondary winding;
- said first and second MOSFETS connected to each other in series across a direct current input source and forming a common MOSFET node therebetween at said first MOSFET source and said second MOSFET drain;
- an input capacitor connected across said direct current input source and having a first capacitor node connected to said first MOSFET drain and a second capacitor node connected to said second MOSFET source;
- a main transformer comprising a primary winding and a first resonant output winding;
- said main transformer primary winding connected between said common MOSFET node and said second capacitor node;
- wherein a first tap of said first resonant output winding is connected to a first tap of said first sensing primary winding, a second tap of said first resonant output winding is connected to a first load terminal of a first load, and a second tap of said first sensing primary winding is connected to a second load terminal of said first load;
- wherein said gate drive transformer further comprises a protection diode winding connected in parallel with a pair of parallel voltage limiting diodes, said voltage limiting diodes having opposite orientations;
- a compensation capacitor connected between the gate and source of each MOSFET to provide resonant oscillation with said first secondary winding and said second secondary winding; and
- a damping resistor connected in series between each of said MOSFET gates and its corresponding secondary winding on said gate drive transformer.

9. (Currently Amended) The converter according to claim 8 [[3]] further comprising one or more additional loads connected across corresponding additional output windings on said main transformer wherein said first load is required to remain connected in a closed circuit with said first resonant output windings and said first sensing primary winding.

10. (Currently Amended) The converter according to claim 8 [[3]] further comprising one or more additional loads connected across corresponding additional output windings on said main transformer; and a dedicated resonant output winding on said main transformer operatively connected to a corresponding dedicated primary sense winding on said gate drive transformer.

11. (Currently Amended) The converter according to claim 8 [[3]] further comprising a compensation capacitor connected between the gate and source of each MOSFET to provide resonant oscillation with said first secondary winding and said second secondary winding.

12. (Currently Amended) The converter according to claim 8 [[3]] further comprising a damping resistor connected in series between each of said MOSFET gates and its corresponding secondary winding on said gate drive transformer.

13. (Currently Amended) The converter according to claim 8 [[3]] wherein said gate drive switching transformer further comprises a protection diode winding connected in parallel with a pair of parallel voltage limiting diodes, said voltage limiting diodes having opposite orientations.

14. (Original) An adaptive resonant power converter comprising:  
a gate drive transformer comprising a first sensing primary winding, a first secondary winding, and a second secondary winding;  
a first MOSFET having a gate connected to said first secondary winding;  
a second MOSFET having a gate connected to said second secondary winding;  
said first and second MOSFETS connected to each other in series across a direct current input source and forming a common MOSFET node therebetween at said first MOSFET source and said second MOSFET drain;  
a first and second input capacitor connected to each other in series across said direct current input source and forming a common capacitor node therebetween;  
a main transformer comprising a primary winding and a first resonant output winding;  
said primary winding connected between said common MOSFET node and said common capacitor node; and  
wherein a first tap of said first resonant output winding is connected to a first tap of said first sensing primary winding, a second tap of said first resonant output winding is connected to a first load terminal of said first load, and a second tap of said first sensing primary winding is connected to a second load terminal of said first load.

15. (Original) The converter according to claim 14 further comprising  
a first rectifier diode connected between said first resonant output winding and  
said first load terminal;  
a capacitor connected across said load from said first load terminal to said second  
load terminal;  
a second output circuit having second resonant output winding on said main  
transformer with the same number of turns as said first resonant output  
winding;  
a second sensing primary winding on said gate drive transformer having the same  
number of turns as said first primary output winding;  
wherein a first tap of said second resonant output winding is connected to a first  
tap of said second sensing primary winding, a second tap of said second  
resonant output winding is connected through said second rectifier diode  
to a first load terminal, and a second tap of said second sensing primary  
winding is connected to said second load terminal;  
a second rectifier diode connected between said first load terminal and said  
second resonant output winding such that said first and second rectifier  
diodes are oriented in the same direction relative to said load.

16. (Original) The converter according to claim 14 further comprising one or  
more additional loads connected across corresponding additional output windings on said  
main transformer wherein said first load is required to remain connected in a closed  
circuit with said first resonant output windings and said first sensing primary winding.

17. (Original) The converter according to claim 14 further comprising one or  
more additional loads connected across corresponding additional output windings on said  
main transformer; and a dedicated resonant output winding on said main transformer  
operatively connected to a corresponding dedicated primary sense winding on said gate  
drive transformer.

18. (Original) The converter according to claim 14 further comprising a compensation capacitor connected between the gate and source of each MOSFET to provide resonant oscillation with said first secondary winding and said second secondary winding.

19. (Original) The converter according to claim 14 further comprising a damping resistor connected in series between each of said MOSFET gates and its corresponding secondary winding on said gate drive transformer.

20. (Currently Amended) The converter according to claim 14 wherein said gate drive switching transformer further comprises a protection diode winding connected in parallel with a pair of parallel voltage limiting diodes, said voltage limiting diodes having opposite orientations.

21. (Original) The converter according to claim 15 further comprising one or more additional loads connected across corresponding additional resonant output windings on said main transformer wherein said first load is required to remain connected in a closed circuit with said first resonant output windings and said first sensing primary winding.

22. (Original) The converter according to claim 15 further comprising one or more additional loads connected across corresponding additional output windings on said main transformer; and a dedicated resonant output winding on said main transformer operatively connected to a corresponding dedicated primary sense winding on said gate drive transformer.

23. (Original) The converter according to claim 15 further comprising a compensation capacitor connected between the gate and source of each MOSFET to provide resonant oscillation with said first secondary winding and said second secondary winding.

24. (Original) The converter according to claim 15 further comprising a damping resistor connected in series between each of said MOSFET gates and its corresponding secondary winding on said gate drive transformer.

25. (Currently Amended) The converter according to claim 15 wherein said gate drive switching transformer further comprises a protection diode winding connected in parallel with a pair of parallel voltage limiting diodes, said voltage limiting diodes having opposite orientations.

26. – 32. (Canceled)